



This technology is currently not available for licensing

Tech ID: 18968

ADDITIONAL TECHNOLOGIES BY THESE INVENTORS

- ▶ [Vertical Cavity Surface-Emitting Lasers with Continuous Wave Operation](#)
- ▶ [Eliminating Misfit Dislocations with In-Situ Compliant Substrate Formation](#)
- ▶ [III-Nitride-Based Vertical Cavity Surface Emitting Laser \(VCSEL\) with a Dielectric P-Side Lens](#)
- ▶ [III-Nitride Tunnel Junction LED with High Wall Plug Efficiency](#)
- ▶ [Novel Multilayer Structure for High-Efficiency UV and Far-UV Light-Emitting Devices](#)
- ▶ [A Method To Lift-Off Nitride Materials With Electrochemical Etch](#)
- ▶ [High-Intensity Solid State White Laser Diode](#)
- ▶ [Nitride Based Ultraviolet LED with an Ultraviolet Transparent Contact](#)
- ▶ [High-Efficiency and High-Power III-Nitride Devices Grown on or Above a Strain Relaxed Template](#)
- ▶ [III-Nitride Based VCSEL with Curved Mirror on P-Side of the Aperture](#)

